

Title (en)

METHOD FOR THE PRODUCTION OF A MONOCRYSTALLINE LAYER ON A SUBSTRATE WITH A NON-ADAPTED LATTICE AND COMPONENT CONTAINING ONE OR SEVERAL SUCH LAYERS

Title (de)

VERFAHREN ZUR HERSTELLUNG EINER EINKRISTALLINEN SCHICHT AUF EINEM NICHT GITTERANGEPASSTEM SUBSTRAT, SOWIE EINE ODER MEHRERE SOLCHER SCHICHTEN ENTHALTENDES BAUELEMENT

Title (fr)

PROCEDE DE PRODUCTION D'UNE COUCHE MONOCRYSTALLINE SUR UN SUBSTRAT SANS ADAPTATION DE RESEAU, ET COMPOSANT COMPORTEANT AU MOINS UNE TELLE COUCHE

Publication

**EP 1051740 A1 20001115 (DE)**

Application

**EP 99907288 A 19990127**

Priority

- DE 9900203 W 19990127
- DE 19802977 A 19980127

Abstract (en)

[origin: DE19802977A1] Production of a single crystal layer on a non-lattice-matched single crystal substrate involves forming a buried defect-rich layer in the substrate. An Independent claim is also included for a component, particularly a blue diode based on a single crystal GaN layer on a sapphire substrate or a transistor, especially a modulated doped field effect transistor (ModFET), with one or more layers produced by the above process. Preferred Features: The buried layer is formed extremely close to the substrate surface, without affecting the surface structure, especially by hydrogen implantation before or after deposition of the surface layer. The substrate material is Si, Ge, GaAs, SiC, sapphire or InP.

IPC 1-7

**H01L 21/20; H01L 21/205**

IPC 8 full level

**C30B 23/02** (2006.01); **H01L 21/20** (2006.01); **H01L 21/265** (2006.01)

CPC (source: EP US)

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Citation (search report)

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